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Kind regards,

Team Nexperia



Medium power Schottky barrier single diode

Rev. 03 — 17 October 2008

**Product data sheet** 

## 1. Product profile

### 1.1 General description

Planar medium power Schottky barrier single diode with an integrated guard ring for stress protection, encapsulated in a SOD323 (SC-76) very small Surface-Mounted Device SMD plastic package.

#### 1.2 Features

- Ultra high-speed switching
- Very low forward voltage
- Guard-ring protected
- Very small SMD plastic package

### 1.3 Applications

- Ultra high-speed switching
- Voltage clamping
- Protection circuits

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_R$	reverse voltage		-	-	20	V
I <sub>F</sub>	forward current		-	-	1	Α
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 1 A	<u>[1]</u> _	480	550	mV

[1] Pulse test:  $t_p \le 300 \ \mu s$ ;  $\delta \le 0.02$ .



### Medium power Schottky barrier single diode

## 2. Pinning information

Table 2. Pinning

Description	Simplified outline	Graphic symbol
cathode	[1]	. 04 -
anode	1 2	1 🔑 2
		sym001
	<b>Description</b> cathode	Description Simplified outline cathode [1]

<sup>[1]</sup> The marking bar indicates the cathode.

# 3. Ordering information

Table 3. Ordering information

Type number	Package	Package					
	Name	Description	Version				
BAT760	SC-76	plastic surface-mounted package; 2 leads	SOD323				

## 4. Marking

Table 4. Marking codes

Type number	Marking code
BAT760	A4

## 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{R}$	reverse voltage		-	20	V
I <sub>F</sub>	forward current		-	1	Α
I <sub>FSM</sub>	non-repetitive peak forward current	t <sub>p</sub> = 8.3 ms; half-sine wave; JEDEC method	-	5	Α
$T_j$	junction temperature		-	125	°C
$T_{amb}$	ambient temperature		-65	+125	°C
$T_{stg}$	storage temperature		-65	+150	°C

2 of 9

### Medium power Schottky barrier single diode

## 6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from	in free air				
	junction to ambient		[1] _	-	220	K/W
			[2] _	-	180	K/W

<sup>[1]</sup> Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for cathode  $10 \times 10 \text{ mm}^2$ .

### 7. Characteristics

Table 7. Characteristics

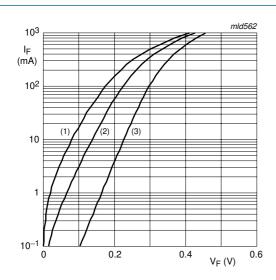
T<sub>amb</sub> = 25 °C unless otherwise specified.

		<u> </u>				
Symbol	Parameter	Conditions	Mi	n Typ	Max	Unit
$V_{F}$	forward voltage		<u>[1]</u>			
		$I_F = 10 \text{ mA}$	-	240	270	mV
		$I_F = 100 \text{ mA}$	-	300	350	mV
		I <sub>F</sub> = 1 A	-	480	550	mV
I <sub>R</sub> reverse current			[1]			
		$V_R = 5 V$	-	5	10	μΑ
		$V_R = 8 V$	-	7	20	μΑ
		V <sub>R</sub> = 15 V	-	10	50	μΑ
$C_{d}$	diode capacitance	$V_R = 5 V$ ; $f = 1 MHz$	-	19	25	рF

<sup>[1]</sup> Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

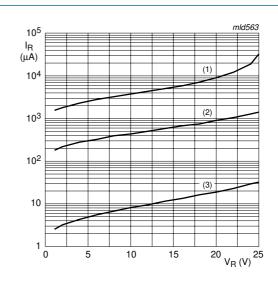
<sup>[2]</sup> Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode  $40 \times 40 \text{ mm}^2$ .

### Medium power Schottky barrier single diode



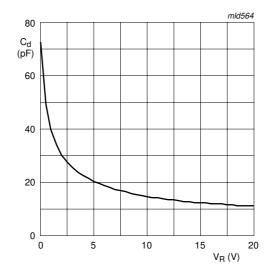
- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$

Fig 1. Forward current as a function of forward voltage; typical values



- (1)  $T_{amb} = 125 \, ^{\circ}C$
- (2)  $T_{amb} = 85 \, ^{\circ}C$
- (3)  $T_{amb} = 25 \, ^{\circ}C$

Fig 2. Reverse current as a function of reverse voltage; typical values

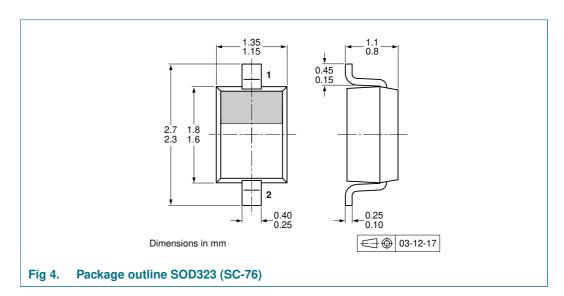


 $f = 1 \text{ MHz}; T_{amb} = 25 \,^{\circ}\text{C}$ 

Fig 3. Diode capacitance as a function of reverse voltage; typical values

### Medium power Schottky barrier single diode

## 8. Package outline



# 9. Packing information

Table 8. Packing methods

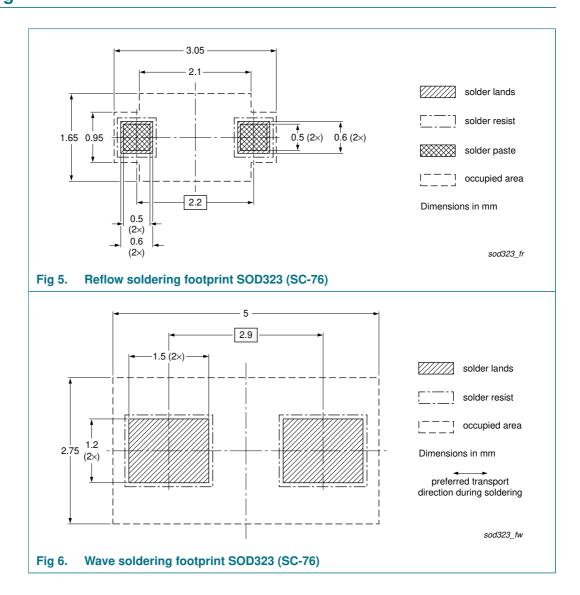
The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity	
			3000	10000
BAT760	SOD323	4 mm pitch, 8 mm tape and reel	-115	-135

<sup>[1]</sup> For further information and the availability of packing methods, see Section 13.

### Medium power Schottky barrier single diode

## 10. Soldering



## Medium power Schottky barrier single diode

# 11. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BAT760_3	20081017	Product data sheet	-	BAT760_2		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>					
	<ul> <li><u>Table 1 "Quick reference data"</u>: added</li> <li><u>Figure 4</u>: superseded by minimized package outline drawing</li> </ul>					
	<ul> <li>Section 9 "Pack</li> </ul>	king information": added				
	<ul> <li>Section 10 "Sol</li> </ul>	dering": added				
	Section 12 "Legal information": updated					
BAT760_2	20040126	Product specification	-	BAT760_1		
BAT760_1	20010312	Product specification	-	-		
	20010012	1 Toddot opcomoditori				

### Medium power Schottky barrier single diode

## 12. Legal information

#### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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## Medium power Schottky barrier single diode

## 14. Contents

1	Product profile	1
1.1	General description	1
1.2	Features	1
1.3	Applications	1
1.4	Quick reference data	1
2	Pinning information	2
3	Ordering information	2
4	Marking	
5	Limiting values	2
6	Thermal characteristics	3
7	Characteristics	3
8	Package outline	5
9	Packing information	5
10	Soldering	6
11	Revision history	7
12	Legal information	8
12.1	Data sheet status	8
12.2	Definitions	8
12.3	Disclaimers	
12.4	Trademarks	8
13	Contact information	8
1/1	Contents	a

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